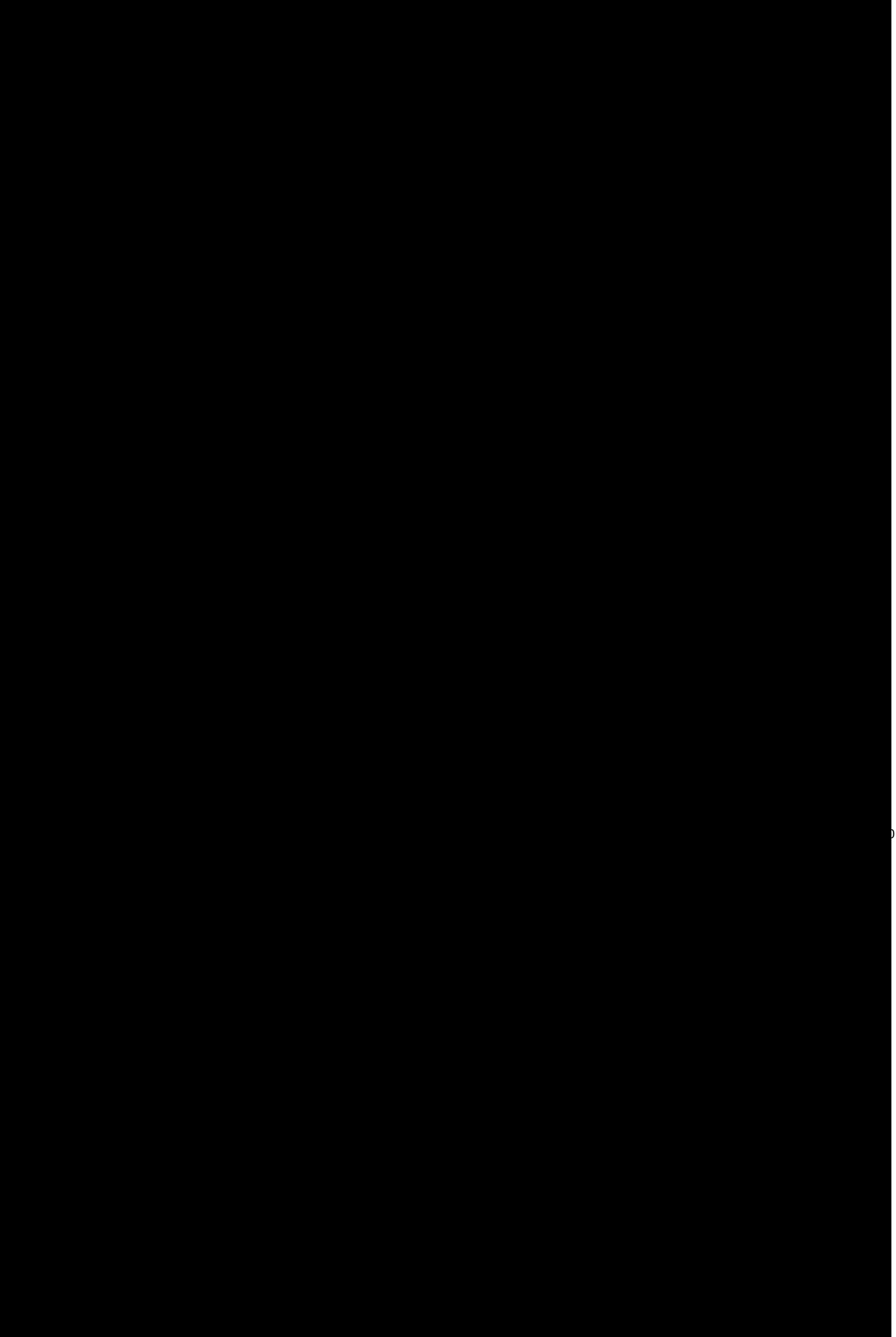

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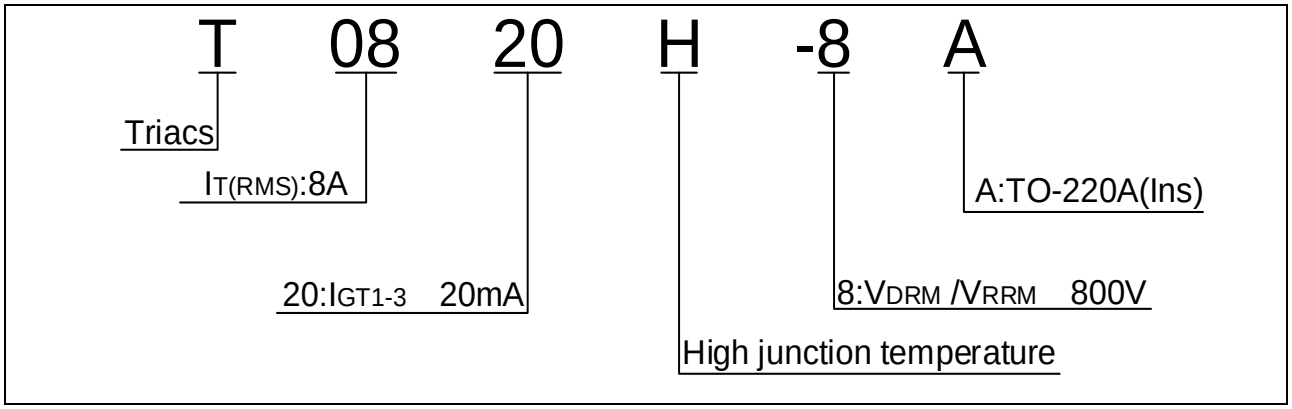
Average gate power dissipation (T_j=150≤)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage (T_j=25≤; non-repetitive,off-state;FIG.7)	V_{pp}	3	kV

ELECTRICAL CHARACTERISTICS (T_j=25≤ unless otherwise specified)

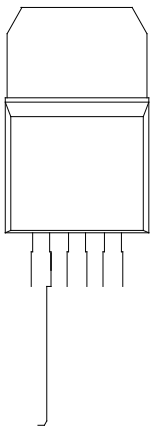
Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D =12V R_L =33	- -	MAX.	20	mA
V_{GT}		- -	MAX	1	V
V_{GD}	V_D =V_{DRM} T_j =150≤ R_L =3.3k	- -	MIN.	0.2	V
I_L	I_G =1.2I_{GT}	-	MAX.	40	mA
				55	

I_H c2 (.2)]TJ 0 Tc 3 Tw 1.11 0 Td ( )Tj EMC /P <</84ID 67 >>BDC 2/C2_1 A

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PACKAGE MECHANICAL DATA

